

HTZ120A Series

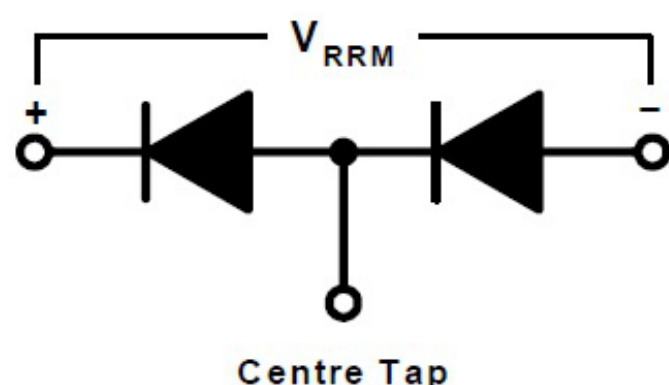
$$I_{F(AV)} = 2.0 \text{ A}$$

$$V_{RRM} = 51000 \text{ V}$$

High Voltage Diode Rectifier Module



CIRCUIT DIAGRAM



CURRENT RATINGS - AIR COOLED

$I_{F(AV)}$	Mean forward current	Half wave resistive load $T_{amb} = 35^{\circ}\text{C}$	2.0	A
I_F	Continuous (direct) forward current	$T_{amb} = 35^{\circ}\text{C}$	2.4	A
$R_{th(j-a)}$	Thermal resistance junction to ambient		2.3	$^{\circ}\text{C/W}$

CURRENT RATINGS - OIL COOLED

$I_{F(AV)}$	Mean forward current	Half wave resistive load $T_{oil} = 60^{\circ}\text{C}$	3.3	A
I_T	Continuous (direct) forward current	$T_{oil} = 60^{\circ}\text{C}$	4.1	A
$R_{th(j-o)}$	Thermal resistance junction to oil		0.93	$^{\circ}\text{C/W}$

SURGE RATINGS

I^2t	I^2t for fusing	10 ms half sine $T_{vj} = 150^{\circ}\text{C}$	200	A^2sec
I_{FSM}	Surge (non-repetitive) forward current	$T_{vj} = 150^{\circ}\text{C}$	200	A

TEMPERATURE AND FREQUENCY RATINGS

T_{vj}	Virtual junction temperature	Forward (conducting)	180	$^{\circ}\text{C}$
		Reverse (blocking)	180	$^{\circ}\text{C}$
T_{stg}	Storage temperature range		-40 to 100	$^{\circ}\text{C}$
f	Frequency range		20 to 400	Hz

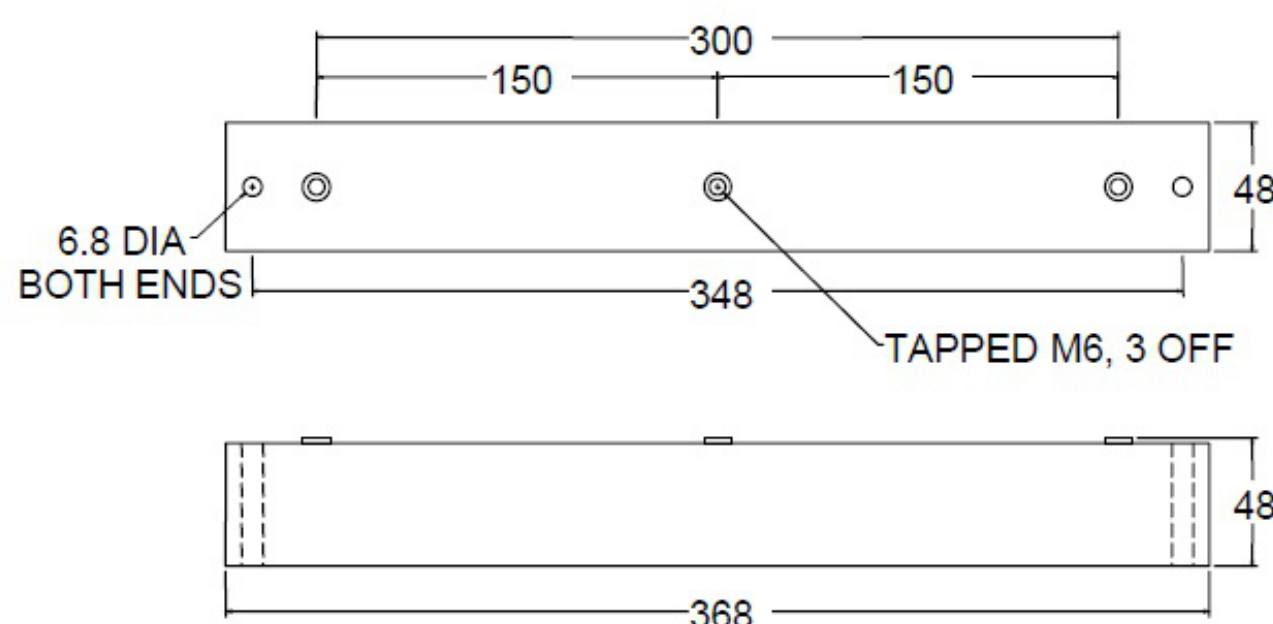
CHARACTERISTICS $T_{case} = 25^{\circ}\text{C}$ unless otherwise stated

V_{FM}	Forward voltage	At 12 Amps peak	max 36.8	V
I_{RM}	Peak reverse current	At V_{RRM} ; $T_{case} = 150^{\circ}\text{C}$	max 0.5	mA

Dimensioned Outlines

Dimensions shown are maximum in mm

Weight typ.: 1,66 Kg



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